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# KA258/KA258A, KA358/KA358A, KA2904

# **Dual Operational Amplifier**

### **Features**

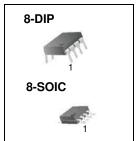
- Internally Frequency Compensated for Unity Gain
- Large DC Voltage Gain: 100dB
- Wide Power Supply Range: KA258/KA258A, KA358/KA358A: 3V ~ 32V (or ±1.5V~ 16V)

 $KA2904 : 3V \sim 26V \text{ (or } \pm 1.5V \sim 13V)$ 

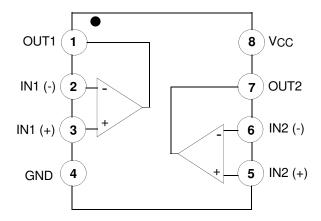
- Input Common Mode Voltage Range Includes Ground
- Large Output Voltage Swing: 0V DC to Vcc 1.5V DC
- Power Drain Suitable for Battery Operation.

### **Description**

The KA258 series consist of two independent, high gain, internally frequency compensated operational amplifiers which were designed specifically to operate from a single power supply over a wide range of voltage. Operation from split power supplies is also possible and the low power supply current drain is independent of the magnitude of the power supply voltage. Application areas include transducer amplifier, DC gain blocks and all the conventional OP-AMP circuits which now can be easily implemented in single power supply systems.

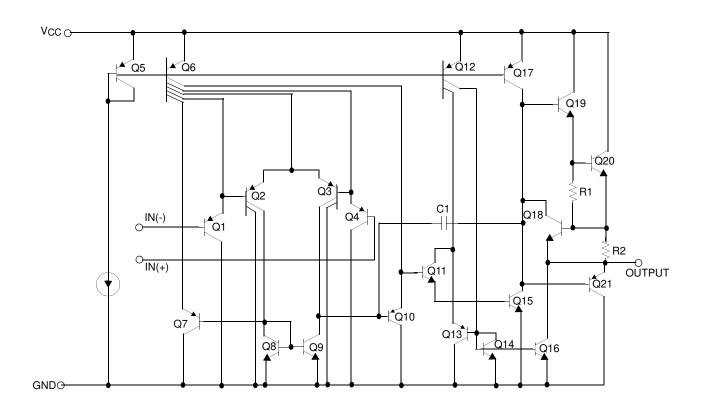


# **Internal Block Diagram**



# **Schematic Diagram**

(One section only)



# **Absolute Maximum Ratings**

Parameter	Symbol	KA258/KA258A	KA358/KA358A	KA2904	Unit
Supply Voltage	Vcc	±16 or 32	±16 or 32	±13 or 26	V
Differential Input Voltage	V <sub>I</sub> (DIFF)	32	32	26	V
Input Voltage	Vı	-0.3 to +32	-0.3 to +32	-0.3 to +26	V
Output Short Circuit to GND VCC≤15V, TA = 25°C(One Amp)	-	Continuous	Continuous	Continuous	-
Operating Temperature Range	TOPR	-25 ~ +85	0 ~ +70	-40 ~ +85	°C
Maximum Junction Temperature	T <sub>J</sub> (MAX)	+150	+150	+150	°C
Storage Temperature Range	TSTG	-65 ~ +150	-65 ~ +150	-65 ~ +150	°C

# **Electrical Characteristics**

 $(V_{CC} = 5.0V, V_{EE} = GND, T_A = 25^{\circ}C, unless otherwise specified)$ 

Davamatav	ameter Symbol Conditions			KA25	8	KA358			l	Unit			
Parameter	Symbol	Condi	tions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	Vio	VCM = 0V  to VO(P) = 1.4V		-	2.9	5.0	-	2.9	7.0	-	2.9	7.0	mV
Input Offset Current	lio	-		-	3	30	-	5	50	-	5	50	nA
Input Bias Current	IBIAS	-		-	45	150	-	45	250	-	45	250	nA
Input Voltage Range	V <sub>I(R)</sub>	VCC = 30V (KA2904, VC	C = 26V)	0	-	VCC -1.5	0	-	VCC -1.5	0	-	VCC -1.5	V
Supply	Icc	RL = ∞, VCC (KA2904, VC		-	0.8	2.0	-	0.8	2.0	-	0.8	2.0	mA
Current	100	$RL = \infty$ , $VCC$	= 5V	-	0.5	1.2	-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	Gv	$V_{CC} = 15V$ , $R_L = 2k\Omega$ $V_{O(P)} = 1V$ to $11V$		50	100	-	25	100	-	25	100	-	V/mV
Output	VO(H)	VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Voltage	30(11)	(VCC = 26V for KA2904)	$R_L = 10k\Omega$	27	28	-	27	28	-	23	24	-	٧
Swing	V <sub>O(L)</sub>	Vcc = 5V, R	L = 10kΩ	-	5	20	-	5	20		5	20	mV
Common- Mode Rejection Ratio	CMRR	-		70	85	-	65	80	-	50	80	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	50	100	-	dB
Channel Separation	CS	f = 1kHz to 2 (Note1)	0kHz	-	120	-	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	-	40	60	mA
	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$		20	30	-	20	30	-	20	30	-	mA
Output Current	•	VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(P) = 2V		10	15	-	10	15	-	10	15	-	mA
ISINK		VI(+) = 0V, VI(-) = 1V VCC = 15V, VO(P) = 200mV		12	100	-	12	100	-	-	-	-	μΑ
Differential Input Voltage	V <sub>I</sub> (DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	V

#### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

### **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the KA258; and the 0 °C  $\leq$  TA  $\leq$  +70°C for the KA358; and the -40°C  $\leq$  TA  $\leq$  +85°C for the KA2904

Dawanatan	O: mala al	Conditions		KA258			KA358				Unit		
Parameter	Symbol	Condi	lions	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
Input Offset Voltage	VIO	$V_{CM} = 0V$ to $V_{O(P)} = 1.4V$		-	-	7.0	-	1	9.0	-	-	10.0	mV
Input Offset Voltage Drift	ΔVΙΟ/ΔΤ	$Rs = 0\Omega$		-	7.0	-	-	7.0	-	-	7.0	-	μV/°C
Input Offset Current	lio	-		-	-	100	-	-	150	-	45	200	nA
Input Offset Current Drift	ΔΙ <sub>ΙΟ</sub> /ΔΤ	-		-	10	-	-	10	-	-	10	-	pA/°C
Input Bias Current	IBIAS	-		-	40	300	-	40	500	-	40	500	nA
Input Voltage Range	V <sub>I(R)</sub>	V <sub>CC</sub> = 30V (KA2904,V <sub>CC</sub> = 26V)		0	-	VCC -2.0	0	-	VCC -2.0	0	-	VCC -2.0	٧
Large Signal Voltage Gain	Gv	$V_{CC} = 15V, R_{L}=2.0k\Omega$ $V_{O}(P) = 1V \text{ to } 11V$		25	-	-	15	-	-	15	-	-	V/mV
Output		VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	22	-	-	V
Voltage Swing	VO(H)	(VCC = 26V for KA2904)	$R_L = 10k\Omega$	27	28	-	27	28	-	23	24	-	V
Swirig	V <sub>O(L)</sub>	$VCC = 5V, RL=10k\Omega$		-	5	20	-	5	20	-	5	20	mV
Output	ISOURCE	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$		10	30	-	10	30	-	10	30	-	mA
Current	ISINK	$V_{I(+)} = 0V, V_{I(-)} = 1V$ $V_{CC} = 15V, V_{O(P)} = 2V$		5	8	-	5	9	-	5	9	-	mA
Differential Input Voltage	VI(DIFF)	-		-	-	Vcc	-	-	Vcc	-	-	Vcc	V

# **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND,  $T_A = 25$ °C, unless otherwise specified)

Dawamatan	Symbol Conditions			ŀ	<b>CA258</b>	BA	ŀ	Unit		
Parameter	Symbol	Conditio	ns	Min.	Тур.	Max.	MIn.	Тур.	Max.	Oilit
Input Offset Voltage	VIO	VCM = 0V to VCC - VO(P) = 1.4V, RS =		-	1.0	3.0	-	2.0	3.0	mV
Input Offset Current	lio	-		-	2	15	-	5	30	nA
Input Bias Current	IBIAS	-		-	40	80	-	45	100	nA
Input Voltage Range	V <sub>I(R)</sub>	VCC = 30V		0	-	VCC -1.5	0	-	VCC -1.5	V
Supply Current	loo	RL = ∞,VCC = 30V		-	0.8	2.0	-	0.8	2.0	mA
Supply Current	Icc	$RL = \infty$ , $VCC = 5V$		-	0.5	1.2	-	0.5	1.2	mA
Large Signal Voltage Gain	Gv	VCC = 15V, R <sub>L</sub> =2ks V <sub>O</sub> = 1V to 11V	$V_{CC}$ = 15V, $R_L$ =2k $\Omega$ $V_O$ = 1V to 11V		100	-	25	100	-	V/mV
0 :	Voн	VCC = 30V	$R_L = 2k\Omega$	26	-	-	26		-	V
Output Voltage Swing			R <sub>L</sub> = 10kΩ	27	28	-	27	28	-	V
Ownig	V <sub>O(L)</sub>	Vcc = 5V, R <sub>L</sub> =10ks	Ω	-	5	20	-	5	20	mV
Common-Mode Rejection Ratio	CMRR	-		70	85	-	65	85	-	dB
Power Supply Rejection Ratio	PSRR	-		65	100	-	65	100	-	dB
Channel Separation	CS	f = 1kHz to $20kHz$ (	(Note1)	-	120	-	-	120	-	dB
Short Circuit to GND	Isc	-		-	40	60	-	40	60	mA
	ISOURCE	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		20	30	-	20	30	-	mA
Output Current	lowur	$V_{I(+)} = 1V, V_{I(-)} = 0V$ $V_{CC} = 15V, V_{O(P)} = 2V$ $V_{In(+)} = 0V, V_{In(-)} = 1V$ $V_{O(P)} = 200mV$		10	15	-	10	15	-	mA
	Isink			12	100	-	12	100	-	μΑ
Differential Input Voltage	VI(DIFF)	-	-	-	Vcc	-	-	Vcc	V	

### Note:

<sup>1.</sup> This parameter, although guaranteed, is not 100% tested in production.

### **Electrical Characteristics** (Continued)

(VCC = 5.0V, VEE = GND, unless otherwise specified) The following specification apply over the range of -25°C  $\leq$  TA  $\leq$  +85°C for the KA258A; and the 0°C  $\leq$  TA  $\leq$  +70°C for the KA358A

Parameter	Symbol Conditions		K	(A258	Α	ŀ	Unit			
Parameter	Symbol	Conditions		Min.	Тур.	Max.	Min.	Тур.	Max.	Oilit
Input Offset Voltage	VIO	$V_{CM} = 0V \text{ to}$ $V_{O(P)} = 1.4V$	-	-	4.0	-	-	5.0	mV	
Input Offset Voltage Drift	ΔV10/ΔΤ		-	-	7.0	15	-	7.0	20	μV/°C
Input Offset Current	ΙO		-	-	-	30	-	-	75	nA
Input Offset Current Drift	ΔΙΙΟ/ΔΤ		-	-	10	200	-	10	300	pA/°C
Input Bias Current	IBIAS		-	-	40	100	1	40	200	nA
Input Common-Mode Voltage Range	V <sub>I(R)</sub>	VCC = 30V		0	-	VCC -2.0	0	-	VCC -2.0	V
	Moun	VCC = 30V	$R_L = 2k\Omega$	26	-	-	26	-	-	V
Output Voltage Swing	V <sub>O(H)</sub>		RL = 10kΩ	27	28	-	27	28	-	V
	V <sub>O(L)</sub>	VCC = 5V, F	R <sub>L</sub> =10kΩ	-	5	20	-	5	20	mV
Large Signal Voltage Gain	Gv		$V_{CC}$ = 15V, R <sub>L</sub> =2.0kΩ $V_{O(P)}$ = 1V to 11V		-	-	15	-	-	V/mV
Output Current	ISOURCE	VI(+) = 1V, VI(-) = 0V VCC = 15V, VO(P) = 2V		10	30	-	10	30	-	mA
Output Current	ISINK	V <sub>I(+)</sub> = 1V, V <sub>I(-)</sub> = 0V V <sub>CC</sub> = 15V, V <sub>O(P)</sub> = 2V		5	9	-	5	9	-	mA
Differential Input Voltage	V <sub>I</sub> (DIFF)		-	-	-	Vcc	-	-	Vcc	V

# **Typical Performance Characteristics**

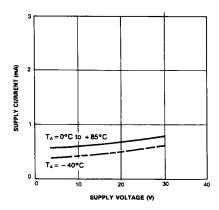
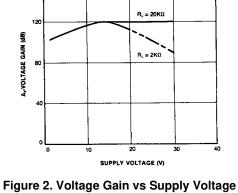


Figure 1. Supply Current vs Supply Voltage



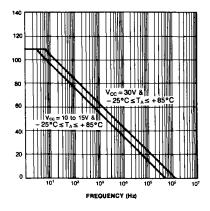


Figure 3. Open Loop Frequency Response

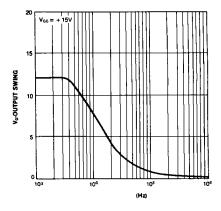


Figure 4. Large Signal Output Swing vs Frequency

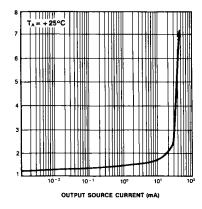


Figure 5. Output Characteristics vs Current Sourcing

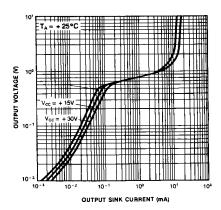


Figure 6. Output Characteristics vs Current Sinking

# **Typical Performance Characteristics** (Continued)

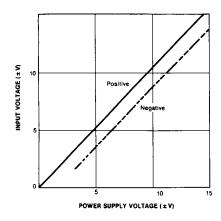


Figure 7. Input Voltage Range vs Supply Voltage

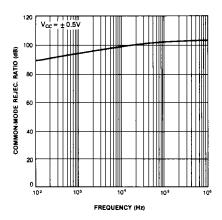


Figure 8. Common-Mode Rejection Ratio

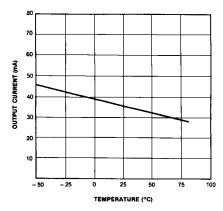


Figure 9. Output Current vs Temperature (Current Limiting)

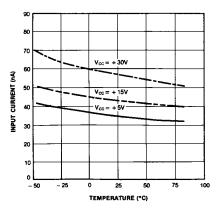


Figure 10. Input Current vs Temperature

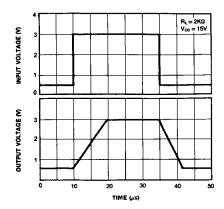


Figure 11. Voltage Follower Pulse Response

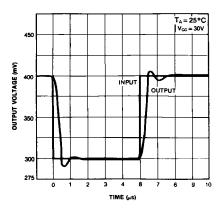
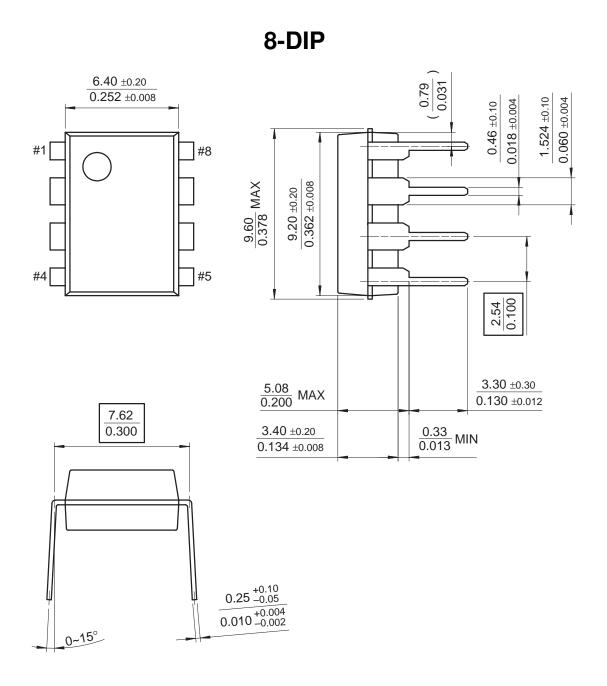


Figure 12. Voltage Follower Pulse Response (Small Signal)

# **Mechanical Dimensions**

### **Package**

### **Dimensions in millimeters**

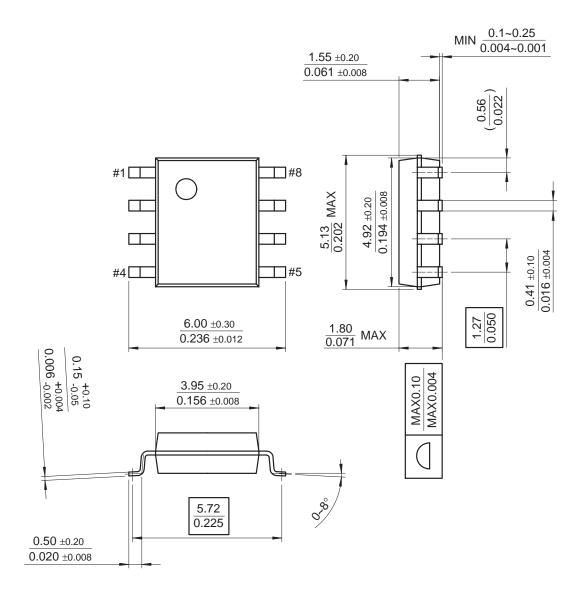


### **Mechanical Dimensions** (Continued)

### **Package**

#### **Dimensions in millimeters**

# 8-SOIC



### **Ordering Information**

Product Number	Package	Operating Temperature
KA358	8-DIP	
KA358A	0-011	0 ∼ +70°C
KA358D	- 8-SOIC	0 4 470 0
KA358AD	0-3010	
KA258D	8-SOIC	-25 ∼ +85°C
KA258AD	8-3010	-25 * +65 C
KA2904	8-DIP	-40 ∼ +85°C
KA2904D	8-SOIC	-40 · +65 C

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